

General Description

The DSC2110FI2-A0008 is a programmable, high performance LVCMOS oscillators utilizing Microchip's proven silicon MEMS technology to provide excellent jitter and stability while incorporating additional device functionality.

The DSC2110FI2-A0008 allows the user to easily modify the frequency using I2C interface. The user can also select from two pre-programmed default output frequencies using the frequency select pin.

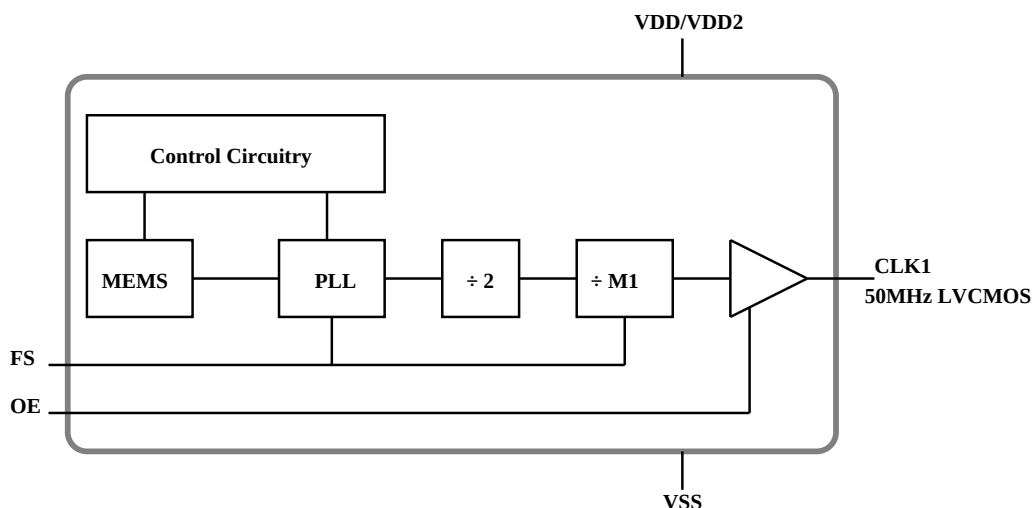
Applications

- Consumer Electronics
- Storage Area Networks
 - SATA, SAS, Fibre Channel
- Passive Optical Networks
 - EPON, 10G-EPON, GPON, 10G-GPON
- Ethernet
 - 1G, 10GBASE-T/KR/LR/SR, and FCoE
- HD/SD/SDI Video & Surveillance
- PCI Express
- Automotive

Features

- Frequency and output formats:
 - LVCMOS
 - 50/25MHz
- Low RMS phase jitter: <1ps (typ)
- ± 25 ppm frequency stability
- -40°C to +85°C industrial temperature range
- High supply noise rejection: -50dBc
- I2C programmable frequency and drive
- Excellent shock & vibration immunity
 - Qualified to MIL-STD-883
- High reliability
 - 20x better MTF than quartz oscillators
- Supply range of 2.25 to 3.6V
- AEC-Q100 automotive qualified
- 14-pin 3.2mm x 2.5mm QFN package

Block Diagram



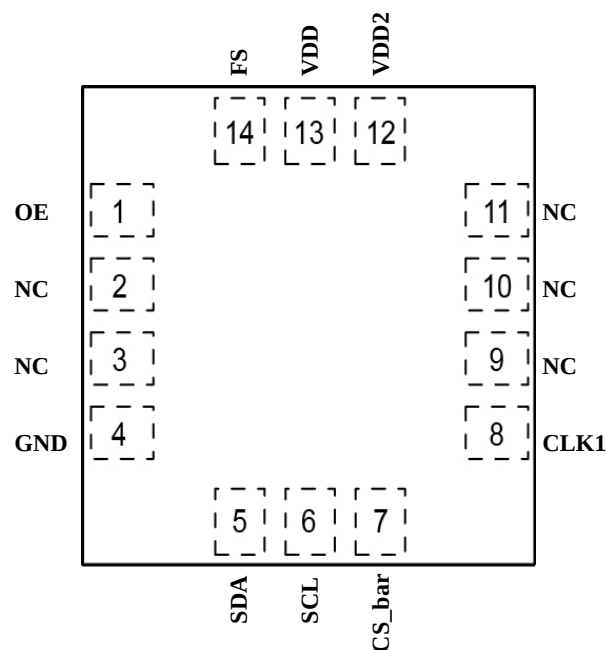
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Ordering Information

Ordering Part Number	Industrial Temperature Range	Shipping	Package
DSC2110FI2-A0008	-40°C to +85°C	Tube	14-pin 3.2mm x 2.5mm QFN
DSC2110FI2-A0008T	-40°C to +85°C	Tape and Reel	14-pin 3.2mm x 2.5mm QFN

Devices are Green and RoHS compliant. Sample material may have only a partial top mark.

Pin Configuration



14-pin 3.2mm x 2.5mm QFN

Pin Description

Pin Number	Pin Name	Pin Type	Pin Function
1	OE	I	Enables outputs when high and disables outputs when low
2	NC		Leave unconnected or connect to ground
3	NC		Leave unconnected or connect to ground
4	GND	PWR	Ground
5	SDA	I	I2C serial data
6	SCL	I	I2C serial clock
7	CS_bar		I2C chip select (active low)
8	CLK1	O	LVC MOS output
9	NC		Leave unconnected or connect to ground
10	NC		Leave unconnected or connect to ground
11	NC		Leave unconnected or connect to ground
12, 13	VDD2, VDD	PWR	Power supply
14	FS	I	Frequency select pin, see Table 2 for details

Operational Description

The DSC2110FI2-A0008 is a LVCMOS oscillator consisting of a MEMS resonator and a supporting PLL IC. The LVCMOS output is generated through independent 8-bit programmable dividers from the output of the internal PLL.

DSC2110FI2-A0008 allows for easy programming of the output frequencies using I2C interface. Upon power-up, the initial output frequency is controlled by an internal pre-programmed memory (OTP). This memory stores all coefficients required by the PLL for two different default frequencies. The control pin (FS) selects the initial frequency. Once the device is powered up, a new output frequency can be programmed. Programming details are provided in the Programming Guide.

When OE (pin 1) is floated or connected to VDD, the DSC2110FI2-A0008 is in operational mode. Driving OE to ground will disable both output drivers (hi-impedance mode).

DSC2110FI2-A0008 has programmable output drive strength, which can be controlled via I2C.

Table 1 displays typical rise / fall times for the output with a 15pF load capacitance as a function of these control bits at VDD = 3.3V and room temperature.

	Output Drive Strength Bits [OS2, OS1, OS0] - Default is [111]							
	000	001	010	011	100	101	110	111
tr (ns)	2.1	1.7	1.6	1.4	1.3	1.3	1.2	1.1
tf (ns)	2.5	2.4	2.4	2	1.8	1.6	1.3	1.3

Table 1. Rise/Fall Times for Drive Strengths

Output Clock Frequencies

Frequency select bits are weakly tied high so if left unconnected the default setting will be [1] and the device will output the associated frequency highlighted in bold.

Freq (MHz)	Freq Select Bit [FS] - Default is [1]	
	0	1
CLK1	25	50

Table 2. Pin-Selectable Output Frequencies

Absolute Maximum Ratings

Item	Min.	Max.	Units	Condition
Supply Voltage	-0.3	+4.0	V	
Input Voltage	-0.3	VDD + 0.3	V	
Junction Temp	-	+150	°C	
Storage Temp	-55	+150	°C	
Soldering Temp	-	+260	°C	40sec max.
ESD				
HBM		4000		
MM		400	V	
CDM		1500		

1000+ years of data retention on internal memory

Specifications (Unless specified otherwise: T = 25°C, max LVC MOS drive strength)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Units
Supply Voltage ¹	VDD		2.25		3.6	V
Supply Current	IDD	OE pin low - output is disabled		21	23	mA
Frequency Stability	ΔF	Includes frequency variation due to initial tolerance, temp. and power supply voltage			± 25	ppm
Aging	ΔF	First year (@ 25°C)			± 5	ppm
Startup Time ²	tSU	T = 25°C			5	ms
Input Logic Levels Input Logic High Input Logic Low	VIH VIL		0.75 x VDD -		- 0.25 x VDD	V
Output Disable Time ³	tDA				5	ns
Output Enable Time ³	tEN				20	ns
Pull-Up Resistor ⁴		Pull-up exists on all digital IO		40		kOhms
LVC MOS Output						
Supply Current ⁴	IDD	OE pin high - output is enabled CL = 15pF, F0 = 125MHz		31	35	mA
Output Logic Levels Output Logic High Output Logic Low	VOH VOL	I = ± 6 mA	0.9 x VDD -		- 0.1 x VDD	V
Output Transition Time ³ Rise Time Fall Time	tR tF	20% to 80% CL = 15pF		1.1 1.3	2 2	ns
Frequency	CLK1	[FS] = [1]		50		MHz
Output Duty Cycle	SYM		45		55	%
Period Jitter	JPER	F0 = 125MHz		3		psRMS
Integrated Phase Noise	JPH	200kHz to 20MHz @ 125MHz 100kHz to 20MHz @ 125MHz 12kHz to 20MHz @ 125MHz		0.3 0.38 1.7	2	psRMS

Notes:

1. Pin 12 VDD2, and pin 13 VDD should be filtered with 0.1uF capacitors.
2. tSU is time to 100ppm stable output frequency after VDD is applied and outputs are enabled.
3. Output Waveform and Test Circuit figures below define the parameters.
4. Output is enabled if OE pin is floated or not connected.

Nominal Performance Parameters (Unless specified otherwise: T = 25°C, VDD = 3.3V)

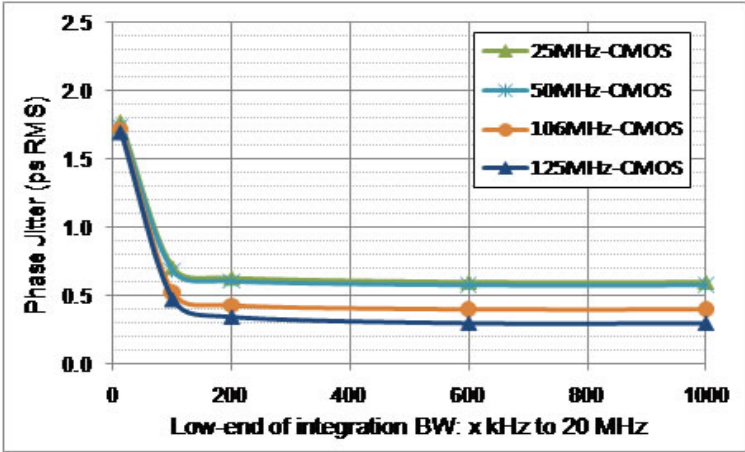


Figure 1. LVC MOS Phase Jitter (integrated phase noise)

LVC MOS Output Waveform

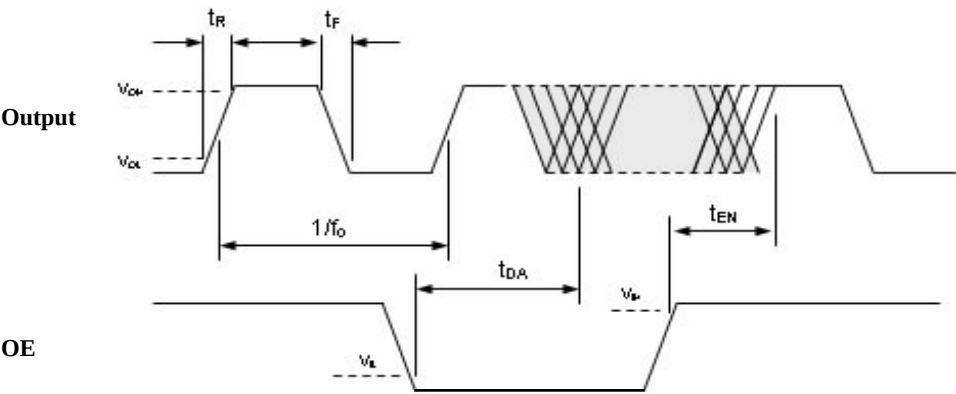


Figure 2. LVC MOS Output Waveform

MSL 1 @ 260°C refer to JSTD-020C	
Ramp-Up Rate (200°C to Peak Temp)	3°C/sec Max.
Preheat Time 150°C to 200°C	60 - 180 sec
Time maintained above 217°C	60 - 150 sec
Peak Temperature	255 - 260°C
Time within 5°C of actual Peak	20 - 40 sec
Ramp-Down Rate	6°C/sec Max.
Time 25°C to Peak Temperature	8 min Max.

Solder Reflow Profile

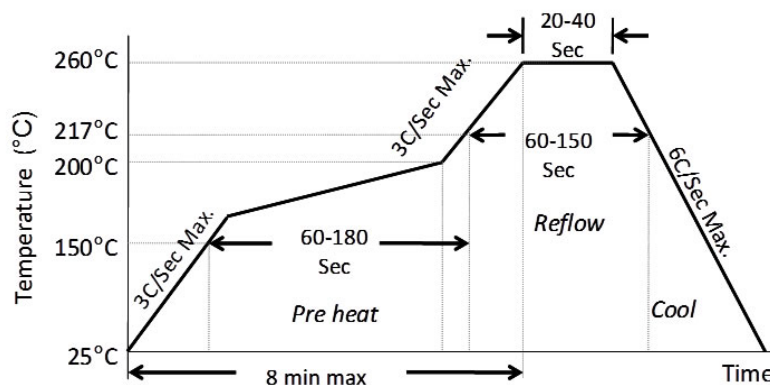
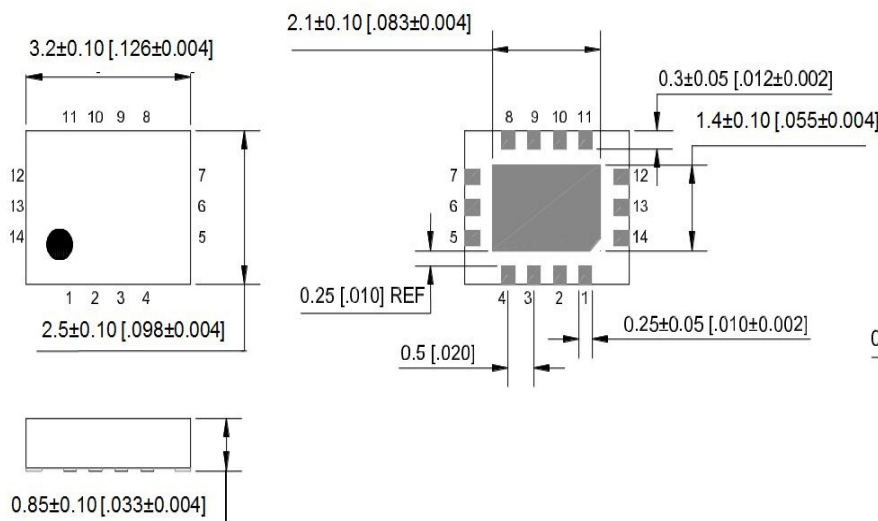


Figure 3. Solder Reflow Profile

Package Information⁶

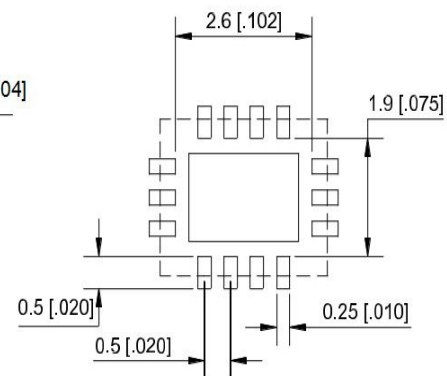
External Dimensions

units: mm[inch]



Recommended Solder Pad Layout

units: mm[inch]



3.2mm x 2.5mm 14 Lead Plastic Package

Notes:

5. Connect the exposed die paddle to ground.

6. Package information is correct as of the publication date. For updates and most current information, go to www.microchip.com.

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